DECDES.



DRDNB21D

COMPLEX ARRAY FOR DUAL RELAY DRIVER

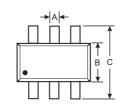
Features

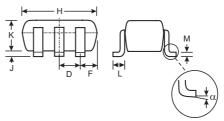
- Epitaxial Planar Die Construction
- Two Pre-Biased Transistors and Two Switching Diodes, Internally Connected in One Package
- Ideally Suited for Automated Assembly Processes
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- Qualified to AEC-Q101 standards for High Reliability

Mechanical Data

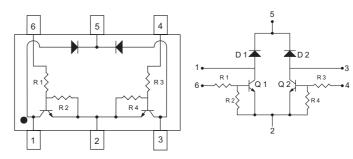
- Case: SOT-363
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Marking & Type Code Information: See Last Page
- Ordering Information: See Last Page
- Weight: 0.006 grams (approximate)

$R1 = R3 = 2.2k\Omega$ (nominal)	
$R2 = R4 = 47k\Omega$ (nominal)	





	SOT-363						
Dim	Min	Max					
Α	0.10	0.30					
В	1.15	1.35					
С	2.00	2.20					
D	0.65 N	ominal					
F	0.30 0.40						
Н	1.80 2.20						
J	_	0.10					
K	0.90 1.00						
L	0.25	0.40					
M	0.10 0.25						
α	0°	8°					
All Dimensions in mm							



Maximum Ratings, Total Device @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3)	P _d	200	mW
Thermal Resistance, Junction to Ambient Air (Note 3)	$R_{ heta JA}$	625	°C/W
Operating and Storage Junction Temperature Range	T _j , T _{STG}	-55 to +150	°C

Maximum Ratings, Pre-Biased NPN Transistor @ TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CC}	50	V
Collector-Emitter Voltage	V _{in}	-5 to +12	V
Emitter-Base Voltage	Io	100	mA
Output Current - Continuous (Note 3)	Ic	200	mA

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 3. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



Maximum Ratings, Switching Diode @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Non-Repetitive Peak Reverse Voltage	V _{RM}	100	V
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	75	V
RMS Reverse Voltage	V _{R(RMS)}	53	V
Forward Continuous Current (Note 3)	I _{FM}	500	mA
Average Rectified Output Current (Note 3)	Io	250	mA
Non-Repetitive Peak Forward Surge Current @ $t = 1.0 \mu s$ @ $t = 1.0 s$	I _{FSM}	4.0 2.0	А

Electrical Characteristics, Pre-Biased NPN Transistor @ TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Input Voltage	V _{I(off)}	0.5	_	_	V	$V_{CC} = 5V$, $I_O = 100 \mu A$
input voltage	V _{I(on)}	_	_	1.1	V	$V_O = 0.3V, I_O = 5mA$
Output Voltage	V _{O(on)}	_	_	0.3	V	$I_0/I_1 = 50 \text{mA}/0.25 \text{mA}$
Input Current	II	_	_	3.6	mA	$V_I = 5V$
Output Current	I _{O(off)}	_	_	0.5	uA	$V_{CC} = 50V, V_I = 0V$
DC Current Gain	Gı	80	_	_	_	$V_O = 5V, I_O = 10mA$
Input Resistor Tolerance	ΔR1	-30	_	+30	%	
Resistance Ratio Tolerance	ΔR2/R1	-20	_	+20	%	
Gain-Bandwidth Product*	f⊤	_	250	_	MHz	$V_{CE} = 10V$, $I_E = 5mA$, $f = 100MHz$

Transistor - For Reference Only

Electrical Characteristics, Switching Diode @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 4)	V _{(BR)R}	75		٧	I _R = 10μA
Forward Voltage (Note 4)	V _F	0.62 — — —	0.72 0.855 1.0 1.25	V	I _F = 5.0mA I _F = 10mA I _F = 100mA I _F = 150mA
Reverse Current (Note 4)	I _R	_	2.5 50 30 25	μΑ μΑ μΑ nA	$\begin{tabular}{lll} $V_R = 75V$ \\ $V_R = 75V$, $T_j = 150^{\circ}C$ \\ $V_R = 25V$, $T_j = 150^{\circ}C$ \\ $V_R = 20V$ \\ \end{tabular}$
Total Capacitance	Ст	_	4.0	pF	V _R = 0, f = 1.0MHz
Reverse Recovery Time	t _{rr}	_	4.0	ns	$I_F = I_R = 10 \text{mA},$ $I_{rr} = 0.1 \text{ x } I_R, R_L = 100 \Omega$

Notes: 3. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

4. Short duration pulse test used to minimize self-heating effect.



Device Characteristics

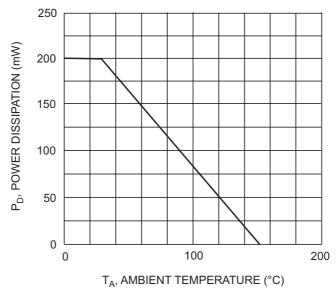
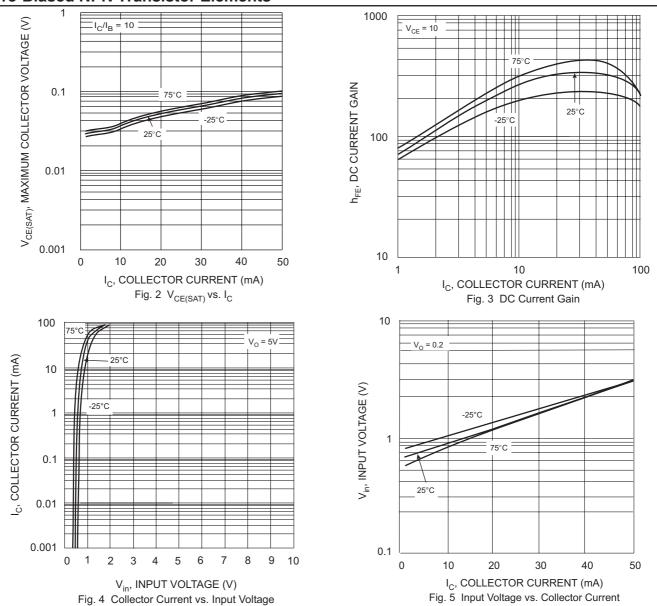


Fig. 1, Power Derating Curve (Total Device)

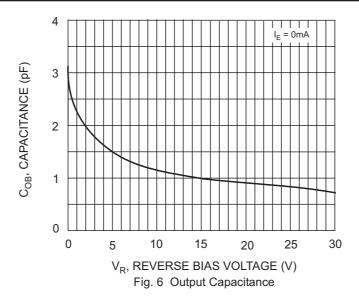
Pre-Biased NPN Transistor Elements



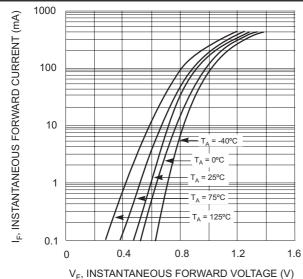
DS30756 Rev. 3 - 2 3 of 5 DRDNB21D



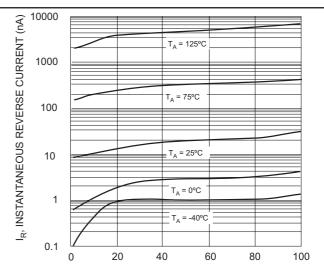
Pre-Biased NPN Transistor Elements (Continued)



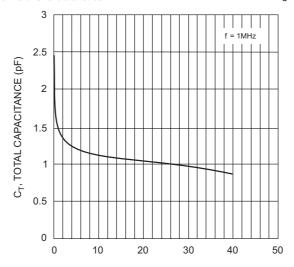
Switching Diode Elements



F, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 7 Typical Forward Characteristics



 V_R , REVERSE VOLTAGE (V) Fig. 8 Typical Reverse Characteristics

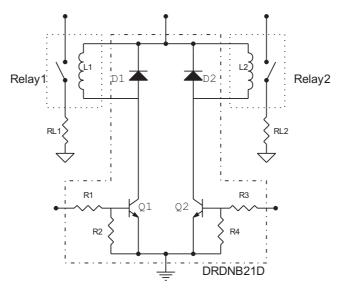


 $\label{eq:VR} {\rm V_{R},\,REVERSE\,\,VOLTAGE\,\,(V)}$ Fig. 9 Typical Capacitance vs. Reverse Voltage

DS30756 Rev. 3 - 2 4 of 5 DRDNB21D



Typical Application Circuit



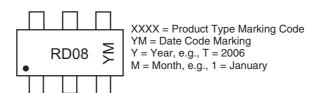
Typical Application Circuit using DRDNB21D with two independent relays.

Ordering Information (Note 5)

Device	Marking Code	Packaging	Shipping	
DRDNB21D-7	RD08	SOT-363	3000/Tape & Reel	

Notes: 5. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



Date Code Key

Year			2005	200	6	2007	2008		2009			
Code			S	Т		U	V		W			
Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

IMPORTANT NOTICE

Diodes, Inc. and its subsidiaries reserve the right to make changes without further notice to any product herein to make corrections, modifications, enhancements, improvements, or other changes. Diodes, Inc. does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

The products located on our website at **www.diodes.com** are not recommended for use in life support systems where a failure or malfunction of the component may directly threaten life or cause injury without the expressed written approval of Diodes Incorporated.